

<b>FORM HDP-1449 (Based on Form PTO-1449)</b>  <b>PATENT AND TRADEMARK OFFICE</b> <b>INFORMATION DISCLOSURE CITATION</b> (Use several sheets if necessary)  Sheet 1 of 1	ATTORNEY DOCKET NO.	SERIAL No. <u>10/720740</u>
	9319S-000577	To be assigned
	APPLICANT	
	Michiru HOGYOKU	
	FILING DATE	GROUP <u>2825</u>
Herewith <u>11/24/03</u>	To be assigned	

U.S. PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Name	Class/ Subclass	(If appropriate) Filing Date
1.						

FOREIGN PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Country	Class/ Subclass	Translation Yes No
1.						

OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)		
Ref. Desig.	Examiner's Initials	
1.	PD	Andy Wei, Melanie J. Sherony, Dimitri A. Antoniadis, "Effect of Floating-Body Charge on SOI MOSFET Design", Vol 45, No. 2, IEEE Transactions on Electron Devices, February 1998.

Examiner: <u>Paul Dinh</u>	Date Considered: <u>1/24/06</u>
----------------------------	---------------------------------

EXAMINER: Please initial if citation considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.